

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO).	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/049,362		02/06/2002	Thomas Gordon Beck Mason	30794.61USWO	1006	
22462	7590	12/27/2004		EXAMINER		
GATES &			NGUYEN, DUNG T			
	HOWARD HUGHES CENTER 6701 CENTER DRIVE WEST, SUITE 1050			ART UNIT	PAPER NUMBER	
LOS ANG	ELES, CA	A 90045		2828		
				DATE MAILED: 12/27/200	4	

Please find below and/or attached an Office communication concerning this application or proceeding.

······································			- 4h				
	Application No.	Applicant(s)	V				
Office Action Summer	10/049,362	MASON ET AL.					
Office Action Summary	Examiner	Art Unit					
<u> </u>	Dung (Michael) T Nguyen	2828					
The MAILING DATE of this communication apperiod for Reply	opears on the cover sheet with th	e correspondence addres	:s				
A SHORTENED STATUTORY PERIOD FOR REPI THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a report of the maximum statutory period for reply within the set or extended period for reply will, by statution Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply b ply within the statutory minimum of thirty (30) d will apply and will expire SIX (6) MONTHS f te, cause the application to become ABANDO	e timely filed days will be considered timely. from the mailing date of this commu DNED (35 U.S.C. § 133).	nication.				
Status							
1) Responsive to communication(s) filed on 111	November 2004.						
	is action is non-final.						
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is							
closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims							
 4) ☐ Claim(s) 1-3 and 5-8 is/are pending in the ap 4a) Of the above claim(s) is/are withdress. 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-3 and 5-8 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/ 	awn from consideration.						
Application Papers							
9)☐ The specification is objected to by the Examin 10)☐ The drawing(s) filed on is/are: a)☐ ac		ao Evominor					
Applicant may not request that any objection to the							
Replacement drawing sheet(s) including the corre			.121(d).				
11) The oath or declaration is objected to by the E	,						
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of: 1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the pri application from the International Burea * See the attached detailed Office action for a list	nts have been received. nts have been received in Applic ority documents have been rece au (PCT Rule 17.2(a)).	cation No eived in this National Stag	ge				
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08	4) ☐ Interview Summ Paper No(s)/Ma 5) ☐ Notice of Inform		2)				
Paper No(s)/Mail Date	6) Other:						

Application/Control Number: 10/049,362

Art Unit: 2828

DETAILED ACTION

Response to Arguments

Applicant's arguments with respect to claims 1-3 and 5-8 have been considered but are moot in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1-3, 5, and 7-8 are rejected under 35 U.S.C. 102(e) as being anticipated by Fish et al. (US6628690).

With respect to claim 1, Fish show in Fig.2 and 3a a tunable 1aser source 10 comprising a widely tunable semiconductor laser comprised of an active region 30 on top of a thick, low bandgap, single common waveguide layer 32, wherein both the waveguide layer and the active region are fabricated between a p-doped region and an n-doped region (it is inherent that the active region and the waveguide are

Art Unit: 2828

usually fabricated between a p-doped region and an n-doped region); and an electro-absorption modulator 30 integrated into the semiconductor laser 12, wherein the electro-absorption modulator shares the waveguide layer with the semiconductor laser, and the waveguide layer is designed to provide high index tuning-efficiency in the laser and good reverse bias-extinction in the modulator (col.4, 1.57-65).

With respect to claim 2, Fish show in Fig.2 the semiconductor laser includes a sampled grating back mirror 20, a phase control section 24, a gain section 22, and a sampled grating front mirror 18.

With respect to claim 3, Fig.2 shows the single common waveguide layer is used for the sampled grating back mirror, phase control section, gain section sampled grating front mirror, and modulator.

With respect to claim 5, Fig.2 and 3a shows the waveguide layer is a buried heterostructure waveguide 32 that includes offset multiple quantum wells (MQW) 30 that provide the laser's output.

Application/Control Number: 10/049,362

Art Unit: 2828

With respect to claim 7, col.5, l.38-44 discloses a blocking junction (ion-implantation) that blocks current leakage in the laser and reduces parasitic junction capacitance of the modulator.

With respect to claim 8, col.4, l.3-6 discloses the semiconductor laser is tuned over a wide wavelength range by proper adjustment of control current for the mirrors.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 6 is rejected under 35 U.S.C. 103(a) as being unpatentable over Fish et al. (US6628690) in view of Sekiguchi et al. (US4896328). Fish disclose all limitations of the claim except for a ridge waveguide. Sekiguchi teach a ridge waveguide (abstract). For the benefit of selecting a waveguide different than of a buried heterostructure waveguide, it would have been obvious to one having

Application/Control Number: 10/049,362

Art Unit: 2828

ordinary skill in the art at the time the invention was made to Fish a ridge waveguide as taught by Sekiguchi.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung (Michael) T Nguyen whose telephone

Application/Control Number: 10/049,362 Page 6

Art Unit: 2828

number is (571) 272-1949. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Harvey, Min can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

MANCH OFFICE OF THE PROPERTY O